

	<p>SI7489DP-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI7489DP-T1-GE3</p>
	<p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p>
	<p>Teil der Beschreibung: MOSFET P-CH 100V 28A PPAK SO-8</p>
<p>Image may be representation. See specs for product details.</p>	<p>Datenblätter:  SI7489DP-T1-GE3.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 800916 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	SI7489DP-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET P-CH 100V 28A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	800916 pcs Stock
Hersteller Standard Vorlaufzeit	33 Weeks
detaillierte Beschreibung	P-Channel 100V 28A (Tc) 5.2W (Ta), 83W (Tc) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	5.2W (Ta), 83W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	28A (Tc)
Rds On (Max) @ Id, Vgs	41 mOhm @ 7.8A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	160nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	4600pF @ 50V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI7489DP-T1-GE3TR



















































SI7489DP-T1-GE3 ist neu im Original, Suche SI7489DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7489DP-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI7489DP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7491DP-T1-E3 Vishay / Siliconix MOSFET P-CH 30V 11A PPAK SO-8</p>	 <p>SI7491DP SI SI7491DP SI</p>	 <p>SI7489DP-T1-GE3 Vishay / Siliconix MOSFET P-CH 100V 28A PPAK SO-8</p>	 <p>SI7489 VISHAY SI7489 VISHAY</p>
 <p>SI7489DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 100V 28A PPAK SO-8</p>	 <p>SI7491DP-T1-GE3 Vishay / Siliconix MOSFET P-CH 30V 11A PPAK SO-8</p>	 <p>SI7491DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 11A PPAK SO-8</p>	 <p>SI7489DP Vishay Precision Group SI7489DP VISHAY</p>

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|  SI7465DP-T1-E3 |  SI7465DP-T1-E3 |  SI7465DP-T1-GE3 |  SI7465DP-T1-GE3 |  SI7470DP-T1-GE3 |
|  SI7476DP-T1-GE3 |  SI7476DP-T1-GE3 |  SI7478DP |  SI7478DP-T1-E3 |  SI7478DP-T1-E3 |
|  SI7478DP-T1-GE3 |  SI7478DP-T1-GE3 |  SI7483ADP |  SI7483ADP-T1-E3 |  SI7483ADP-T1-E3 |
|  SI7483ADP-T1-GE3 |  SI7483ADP-T1-GE3 |  SI7483DP-T1 |  SI7483DP-T1-E3 |  SI7483DP-T1-GE3 |
|  SI7485DP-T1-E3 |  SI7485DP-T1-E3 |  SI7485DP-T1-GE3 |  SI7485DP-T1-GE3 |  SI7489DP |
|  SI7489DP-T1-GE3 |  SI7491DP |  SI7491DP-T1-GE3 |  SI7491DP-T1-GE3 |  SI7501DN-T1-E3 |
|  SI7501DN-T1-E3 |  SI7540ADP-T1-GE3 |  SI7540ADP-T1-GE3 |  SI7540DP-T1-E3 |  SI7540DP-T1-E3 |
|  SI7540DP-T1-GE3 |  SI7540DP-T1-GE3 |  SI7606DN-T1-E3 |  SI7606DN-T1-GE3 |  SI7611DN-T1-GE3 |
|  SI7611DN-T1-GE3 |  SI7613DN-T1-GE3 |  SI7613DN-T1-GE3 |  SI7615ADN-T1-GE3 |  SI7615ADN-T1-GE3 |
|  SI7615DN |  SI7615DN-T1-E3 |  SI7615DN-T1-GE3 |  SI7615DN-T1-GE3 |  SI7617DN-T1-GE3 |

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